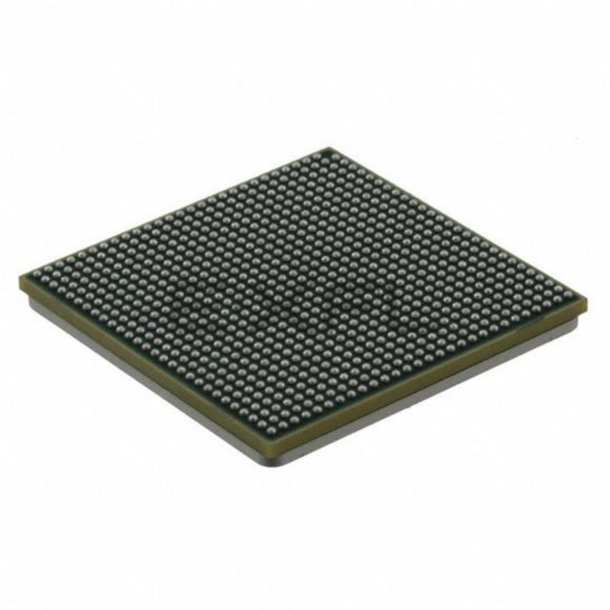

Welcome to E-XFL.COM

Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	PowerPC e500
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	600MHz
Co-Processors/DSP	Security; SEC
RAM Controllers	DDR2, DDR3
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (2)
SATA	SATA 3Gbps (1)
USB	USB 2.0 (2)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	Cryptography
Package / Case	783-BBGA, FCBGA
Supplier Device Package	783-FCPBGA (29x29)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mpc8535ebvtakga

	A	B	C	D	E	F	G	H	J	K	L	M	N	P
1		GV_{DD}	$\overline{\text{MDQS}}$ [5]	MDQ [32]	MDQ [46]	MDQ [47]	MDQ [34]	GND	MDQ [56]	MDQ [57]	GND	GV_{DD}	MDQS [7]	MDQ [58]
2	MDQ [44]	MDQ [40]	MDM [5]	MDQS [5]	GV_{DD}	MDQ [42]	MDQ [43]	MDQ [35]	MDQ [60]	MDQ [61]	MDM [7]	$\overline{\text{MDQS}}$ [7]	GND	MDM [62]
3	GND	MDQ [45]	MDQ [41]	$\overline{\text{MCS}}$ [0]	GND	MDQ [33]	GV_{DD}	MDQ [38]	MDQ [52]	GV_{DD}	MDM [6]	MDQS [6]	MDQ [50]	MDQ [51]
4	MBA [0]	$\overline{\text{MWE}}$	$\overline{\text{MCS}}$ [2]	GV_{DD}	MDQ [36]	GND	MDM [4]	GND	MDQ [39]	MDQ [53]	MDQ [49]	$\overline{\text{MDQS}}$ [6]	MDQ [54]	MDQ [55]
5	MA [10]	MBA [1]	$\overline{\text{MRAS}}$	GND	MODT [0]	GV_{DD}	MDQ [37]	GV_{DD}	$\overline{\text{MDQS}}$ [4]	MDQS [4]	MDQ [48]	GND	GV_{DD}	GND
6	MAPAR_ OUT	NC	GND	GV_{DD}	MODT [2]	MODT [3]	$\overline{\text{MCS}}$ [3]	$\overline{\text{MCS}}$ [1]	MCK [2]	$\overline{\text{MCK}}$ [2]	SD2_ IMP_CAL _TX	SD2_ REF_ CLK	S2GND	SD2_RX [0]
7	GND	MA [0]	GV_{DD}	NC	$\overline{\text{MCAS}}$	MA [13]	GV_{DD}	MODT [1]	NC	GND	SD2_ PLL_ TPD	$\overline{\text{SD2\_REF\_CLK}}$	$S2V_{DD}$	$\overline{\text{SD2\_RX}}$ [0]
8	MCK [3]	$\overline{\text{MCK}}$ [3]	MA [2]	GND	GV_{DD}	GND	MA [1]	MCK [5]	$\overline{\text{MCK}}$ [5]	GND	Rsvd	S2GND	SD2_RX [1]	S2GND
9	MCK [0]	$\overline{\text{MCK}}$ [0]	GV_{DD}	MA [4]	MA [8]	MA [7]	GV_{DD}	MCKE [3]	NC	NC	Rsvd	$S2V_{DD}$	$\overline{\text{SD2\_RX}}$ [1]	S2GND
10	MA [3]	GND	MA [5]	NC	MA [14]	MA [15]	MCKE [2]	MCKE [0]	GV_{DD}	MCKE [1]	NC	X2GND	NC	NC
11	MA [6]	GV_{DD}	MECC [3]	MA [12]	GV_{DD}	MECC [2]	GV_{DD}	$\overline{\text{MCK}}$ [1]	MCK [1]	GND	$X2V_{DD}$	SD2_TX [1]	X2GND	SD2_TX [0]
12	MA [11]	MA [9]	GND	MECC [7]	GND	NC	MECC [0]	GV_{DD}	GND	GV_{DD}	X2GND	$\overline{\text{SD2\_TX}}$ [1]	$X2V_{DD}$	$\overline{\text{SD2\_TX}}$ [0]
13	$\overline{\text{MAPAR\_ERR}}$	MBA [2]	MECC [6]	MDQS [8]	$\overline{\text{MDQS}}$ [8]	MDM [8]	GND	$\overline{\text{MCK}}$ [4]	MCK [4]	VDD_ CORE	GND	VDD_ CORE	GND	VDD_ CORE
14	GND	MDQ [27]	GV_{DD}	MECC [1]	GV_{DD}	MECC [5]	MECC [4]	GV_{DD}	GND	GV_{DD}	VDD_ CORE	GND	VDD_ CORE	GND

DETAIL A

Figure 3. Chip Pin Map Detail A

Table 1. Pinout Listing (continued)

Signal	Signal Name	Package Pin Number	Pin Type	Power Supply	Notes
LAD[0:31]	Muxed data / address	K22,L21,L22,K23,K24, L24,L25,K25,L28,L27, K28,K27,J28,H28,H27, G27,G26,F28,F26,F25, E28,E27,E26,F24,E24, C26,G24,E23,G23,F22, G22,G21	I/O	BV_{DD}	5,9,29
LDP[0:3]	Data parity	K26,G28,B27,E25	I/O	BV_{DD}	29
LA[27]	Burst address	L19	O	BV_{DD}	5,9,29
LA[28:31]	Port address	K16,K17,H17,G17	O	BV_{DD}	5,7,9,29
$\overline{LCS}$[0:4]	Chip selects	K18,G19,H19,H20,G16	O	BV_{DD}	29
$\overline{LCS5}$/$\overline{DMA\_DREQ2}$	Chips selects / DMA Request	H16	I/O	BV_{DD}	1,29
$\overline{LCS6}$/$\overline{DMA\_DACK2}$	Chips selects / DMA Ack	J16	O	BV_{DD}	1,29
$\overline{LCS7}$/$\overline{DMA\_DDONE2}$	Chips selects / DMA Done	L18	O	BV_{DD}	1,29
$\overline{LWE0}$/$\overline{LBS0}$/$\overline{LFWE}$	Write enable / Byte select	J22	O	BV_{DD}	5,9,29
$\overline{LWE[1:3]}$/$\overline{LBS[1:3]}$	Write enable / Byte select	H22,H23,H21	O	BV_{DD}	5,9,29
LBCTL	Buffer control	J25	O	BV_{DD}	5,8,9,29
LALE	Address latch enable	J26	O	BV_{DD}	5,8,9,29
LGPL0/LFCLE	UPM general purpose line 0 / FLash command latch enable	J20	O	BV_{DD}	5,9,29
LGPL1/LFALE	UPM general purpose line 1 / Flash address latch enable	K20	O	BV_{DD}	5,9,29
LGPL2/$\overline{LOE}$/$\overline{LFRE}$	UPM general purpose line 2 / Output enable/Flash read enable	G20	O	BV_{DD}	5,8,9,29
LGPL3/$\overline{LFWP}$	UPM general purpose line 3 / Flash write protect	H18	O	BV_{DD}	5,9,29
LGPL4/$\overline{LGTA}$/LUPWAIT /LPBSE/LFRB	UPM general purpose line 4 / Target Ack/Wait/SDRAM parity byte select/Flash Ready-busy	L20	I/O	BV_{DD}	29, 35
LGPL5	UPM general purpose line 5 / Amux	K19	O	BV_{DD}	5,9,29
LCLK[0:2]	Local bus clock	H24,J24,H25	O	BV_{DD}	29
LSYNC_IN	Synchronization	D27	I	BV_{DD}	29
LSYNC_OUT	Local bus DLL	D28	O	BV_{DD}	29
DMA					
$\overline{DMA\_DACK}$[0:1] /GPIO[10:11]	DMA Acknowledge	AD6,AE10	O	OV_{DD}	—

Table 1. Pinout Listing (continued)

Signal	Signal Name	Package Pin Number	Pin Type	Power Supply	Notes
UART_SOUT[0:1]	Transmit data	AF10,AA12	O	OV_{DD}	5,9,22, 10,29
I^2C interface					
IIC1_SCL	Serial clock	AG21	I/O	OV_{DD}	4,21,29
IIC1_SDA	Serial data	AH22	I/O	OV_{DD}	4,21,29
IIC2_SCL	Serial clock	AH15	I/O	OV_{DD}	4,21,29
IIC2_SDA	Serial data	AG14	I/O	OV_{DD}	4,21,29
SerDes1(x4)					
SD1_TX[7:4]	Transmit Data (+)	Y23,W21,V23,U21	O	XV_{DD}	—
$\overline{\text{SD1\_TX}}$[7:4]	Transmit Data(-)	Y22,W20,V22,U20	O	XV_{DD}	—
SD1_RX[7:4]	Receive Data(+)	AC28,AB26,AA28,Y26	I	XV_{DD}	—
$\overline{\text{SD1\_RX}}$[7:4]	Receive Data(–)	AC27,AB25,AA27,Y25	I	XV_{DD}	—
Reserved	—	R21,P23,N21,M23, R20,P22,N20,M22	—	—	18
Reserved	—	T26,R28,P26,N28, T25,R27,P25,N27	—	—	33
SD1_PLL_TPD	PLL test point Digital	V28	O	XV_{DD}	18
SD1_REF_CLK	PLL Reference clock	U28	I	XV_{DD}	—
$\overline{\text{SD1\_REF\_CLK}}$	PLL Reference clock complement	U27	I	XV_{DD}	—
Reserved	—	T22	—	—	18
Reserved	—	T23	—	—	18
SerDes2(x1)					
SD2_TX[0]	Transmit data(+)	P11	O	$X2V_{DD}$	—
$\overline{\text{SD2\_TX[0]}}$	Transmit data(-)	P12	O	$X2V_{DD}$	—
SD2_RX[0]	Receive data(+)	P6	I	$X2V_{DD}$	—
$\overline{\text{SD2\_RX[0]}}$	Receive data(-)	P7	I	$X2V_{DD}$	—
Reserved	—	M11,M12	—	—	18
Reserved	—	N8, N9	—	—	34
SD2_PLL_TPD	PLL test point Digital	L7	O	$X2V_{DD}$	18
SD2_REF_CLK	PLL Reference clock	M6	I	$X2V_{DD}$	—
$\overline{\text{SD2\_REF\_CLK}}$	PLL Reference clock complement	M7	I	$X2V_{DD}$	—
Reserved	—	L8	—	$X2V_{DD}$	18
Reserved	—	L9	—	$X2V_{DD}$	18

2.4.6 Platform to FIFO Restrictions

Please note the following FIFO maximum speed restrictions based on platform speed. The “platform clock (CCB) frequency” in the following formula refers to the maximum platform (CCB) frequency of the speed bins the part belongs to, which is defined in Table 73.

For FIFO GMII mode:

FIFO TX/RX clock frequency <= platform clock frequency/3.2

For example, if the platform frequency is 533 MHz, the FIFO TX/RX clock frequency should be no more than 167 MHz

For FIFO encoded mode:

FIFO TX/RX clock frequency <= platform clock frequency/3.2

For example, if the platform frequency is 533 MHz, the FIFO TX/RX clock frequency should be no more than 167 MHz

2.4.7 Other Input Clocks

For information on the input clocks of other functional blocks of the platform such as SerDes, and eTSEC, see the specific section of this document.

2.5 RESET Initialization

This section describes the AC electrical specifications for the RESET initialization timing requirements of the chip. This table provides the RESET initialization AC timing specifications for the DDR SDRAM component(s).

Table 10. RESET Initialization Timing Specifications

Parameter/Condition	Min	Max	Unit	Notes
Required assertion time of $\overline{\text{HREST}}$	100	—	µs	—
Minimum assertion time for $\overline{\text{SRESET}}$	3	—	Sysclk	1
PLL input setup time with stable SYSCLK before $\overline{\text{HRESET}}$ negation	100	—	µs	—
Input setup time for POR configurations (other than PLL config) with respect to negation of $\overline{\text{HRESET}}$	4	—	SYSCLKs	1
Input hold time for all POR configurations (including PLL config) with respect to negation of $\overline{\text{HRESET}}$	2	—	SYSCLKs	1
Maximum valid-to-high impedance time for actively driven POR configurations with respect to negation of $\overline{\text{HRESET}}$	—	5	SYSCLKs	1
$\overline{\text{HRESET}}$ rise time	—	1	SYSCLK	—

Notes:
1. SYSCLK is the primary clock input for the chip.

This table provides the PLL lock times.

Table 11. PLL Lock Times

Parameter/Condition	Min	Max	Unit	Notes
PLL lock times	—	100	µs	—
Local bus PLL	—	50	µs	—
PCI bus lock time	—	50	µs	—

Table 25. RGMII, RTBI, and FIFO DC Electrical Characteristics

Parameters	Symbol	Min	Max	Unit	Notes
Supply voltage 2.5 V	LV_{DD}/TV_{DD}	2.37	2.63	V	1,2
Output high voltage (LV_{DD}/TV_{DD} = Min, IOH = –1.0 mA)	V_{OH}	2.00	LV_{DD}/TV_{DD} + 0.3	V	—
Output low voltage (LV_{DD}/TV_{DD} = Min, I_{OL} = 1.0 mA)	V_{OL}	GND – 0.3	0.40	V	—
Input high voltage	V_{IH}	1.70	LV_{DD}/TV_{DD} + 0.3	V	—
Input low voltage	V_{IL}	–0.3	0.70	V	—
Input high current (V_{IN} = LV_{DD}, V_{IN} = TV_{DD})	I_{IH}	—	10	μA	1, 2,3
Input low current (V_{IN} = GND)	I_{IL}	–15	—	μA	3

Note:

1 LV_{DD} supports eTSECs 1.
2 TV_{DD} supports eTSECs 3.
3 Note that the symbol V_{IN}, in this case, represents the LV_{IN} and TV_{IN} symbols referenced in Table 1 and Table 2.

2.9.2 FIFO, GMII, MII, TBI, RGMII, RMII, and RTBI AC Timing Specifications

The AC timing specifications for FIFO, GMII, MII, TBI, RGMII, RMII, and RTBI are presented in this section.

2.9.2.1 FIFO AC Specifications

The basis for the AC specifications for the eTSEC's FIFO modes is the double data rate RGMII and RTBI specifications, since they have similar performance and are described in a source-synchronous fashion like FIFO modes. However, the FIFO interface provides deliberate skew between the transmitted data and source clock in GMII fashion.

When the eTSEC is configured for FIFO modes, all clocks are supplied from external sources to the relevant eTSEC interface. That is, the transmit clock must be applied to the eTSEC*n*'s TSEC*n*_TX_CLK, while the receive clock must be applied to pin TSEC*n*_RX_CLK. The eTSEC internally uses the transmit clock to synchronously generate transmit data and outputs an echoed copy of the transmit clock back out onto the TSEC*n*_GTX_CLK pin (while transmit data appears on TSEC*n*_TXD[7:0], for example). It is intended that external receivers capture eTSEC transmit data using the clock on TSEC*n*_GTX_CLK as a source-synchronous timing reference. Typically, the clock edge that launched the data can be used, since the clock is delayed by the eTSEC to allow acceptable set-up margin at the receiver. Note that there is relationship between the maximum FIFO speed and the platform speed. For more information see Section 2.4.6, "Platform to FIFO Restrictions."

A summary of the FIFO AC specifications appears in the following tables.

Table 26. FIFO Mode Transmit AC Timing Specification

Parameter/Condition	Symbol	Min	Typ	Max	Unit
TX_CLK, GTX_CLK clock period[2]	t_{FIT}	6.0	8.0	100	ns
TX_CLK, GTX_CLK duty cycle	t_{FITH}	45	50	55	%
TX_CLK, GTX_CLK peak-to-peak jitter	t_{FITJ}	—	—	250	ps

This figure shows the GMII transmit AC timing diagram.

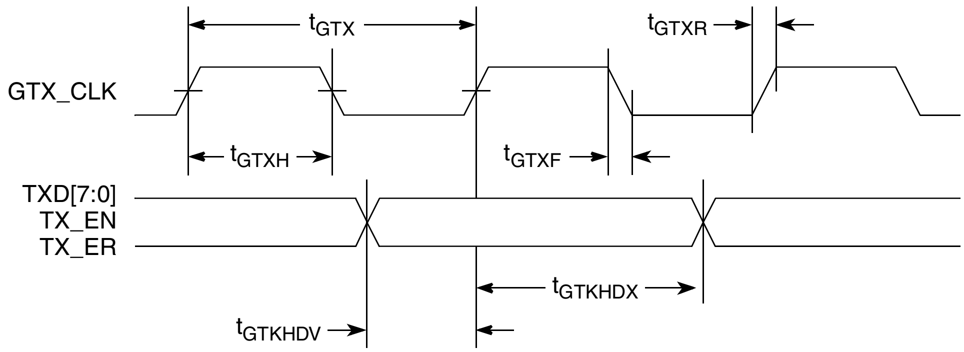

Figure 16. GMII Transmit AC Timing Diagram

2.9.2.2.2 GMII Receive AC Timing Specifications

This table provides the GMII receive AC timing specifications.

Table 29. GMII Receive AC Timing Specifications

At recommended operating conditions with L/TV_{DD} of 3.3 V ± 5%.

Parameter/Condition	Symbol [1]	Min	Typ	Max	Unit
RX_CLK clock period	t_{GRX}	—	8.0	—	ns
RX_CLK duty cycle	t_{GRXH}/t_{GRX}	35	—	65	%
RXD[7:0], RX_DV, RX_ER setup time to RX_CLK	t_{GRDVKH}	2.0	—	—	ns
RXD[7:0], RX_DV, RX_ER hold time to RX_CLK	t_{GRDXKH}	0	—	—	ns
RX_CLK clock rise (20%-80%)	t_{GRXR}	—	—	1.0	ns
RX_CLK clock fall time (80%-20%)	t_{GRXF}	—	—	1.0	ns

Note:

1. The symbols used for timing specifications herein follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state) (reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{GRDVKH} symbolizes GMII receive timing (GR) with respect to the time data input signals (D) reaching the valid state (V) relative to the t_{RX} clock reference (K) going to the high state (H) or setup time. Also, t_{GRDXKL} symbolizes GMII receive timing (GR) with respect to the time data input signals (D) went invalid (X) relative to the t_{GRX} clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{GRX} represents the GMII (G) receive (RX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

This figure provides the AC test load for eTSEC.

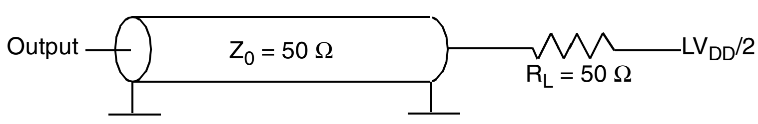

Figure 17. eTSEC AC Test Load

When operating in SGMII mode, the eTSEC EC_GTX_CLK125 clock is not required for this port. Instead, SerDes reference clock is required on SD2_REF_CLK and $\overline{\text{SD2\_REF\_CLK}}$ pins.

2.9.3.1 DC Requirements for SGMII SD2_REF_CLK and SD2_REF_CLK

The characteristics and DC requirements of the separate SerDes reference clock are described in Section 2.20, "High-Speed Serial Interfaces."

2.9.3.2 AC Requirements for SGMII SD2_REF_CLK and $\overline{\text{SD2\_REF\_CLK}}$

This table lists the SGMII SerDes reference clock AC requirements. Please note that SD2_REF_CLK and $\overline{\text{SD2\_REF\_CLK}}$ are not intended to be used with, and should not be clocked by, a spread spectrum clock source.

Table 38. SD2_REF_CLK and $\overline{\text{SD2\_REF\_CLK}}$ AC Requirements

Symbol	Parameter Description	Min	Typical	Max	Units	Notes
t_{REF}	REFCLK cycle time	—	10 (8)	—	ns	1
t_{REFCJ}	REFCLK cycle-to-cycle jitter. Difference in the period of any two adjacent REFCLK cycles	—	—	100	ps	—
t_{REFPJ}	Phase jitter. Deviation in edge location with respect to mean edge location	–50	—	50	ps	2,3

Notes:

1. 8 ns applies only when 125 MHz SerDes2 reference clock frequency is selected via cfg_srds_sgmii_refclk during POR.
2. In a frequency band from 150 kHz to 15 MHz, at BER of 10E-12.
3. Total peak-to-peak deterministic jitter "Dj" should be less than or equal to 50 ps.

Table 40. SGMII DC Receiver Electrical Characteristics (continued)

Parameter	Symbol	Min	Typ	Max	Unit	Notes
Receiver differential input impedance	Z_{RX_DIFF}	80	100	120	Ω	—
Receiver common mode input impedance	Z_{RX_CM}	20	—	35	Ω	—
Common mode input voltage	V_{CM}	—	$V_{xcorevss}$	—	V	6

Notes:
1. Input must be externally AC-coupled.
2. $V_{RX\_DIFFp-p}$ is also referred to as peak to peak input differential voltage
3. The concept of this parameter is equivalent to the Electrical Idle Detect Threshold parameter in PCI Express. See Table 72 for further explanation.
4. The LSTS shown in the table refers to the LSTSA or LSTSE bit field of chip's SerDes 2 control register.
5. V_{CM_ACp-p} is also referred to as peak to peak AC common mode voltage.
6. On-chip termination to S2GND (xcorevss).

2.9.3.4 SGMII AC Timing Specifications

This section describes the SGMII transmit and receive AC timing specifications. Transmitter and receiver characteristics are measured at the transmitter outputs (SD2_TX[n] and $\overline{\text{SD2\_TX}}$[n]) or at the receiver inputs (SD2_RX[n] and $\overline{\text{SD2\_RX}}$[n]) as depicted in Figure 32 respectively.

2.9.3.4.1 SGMII Transmit AC Timing Specifications

This table provides the SGMII transmit AC timing targets. A source synchronous clock is not provided.

Table 41. SGMII Transmit AC Timing Specifications

At recommended operating conditions with $X2V_{DD}$ = 1.0V ± 5%.

Parameter	Symbol	Min	Typ	Max	Unit	Notes
Deterministic Jitter	JD	—	—	0.17	UI p-p	—
Total Jitter	JT	—	—	0.35	UI p-p	—
Unit Interval	UI	799.92	800	800.08	ps	1
V_{OD} fall time (80%-20%)	tfall	50	—	120	ps	—
V_{OD} rise time (20%-80%)	t_{rise}	50	—	120	ps	—

Notes:
1. Each UI is 800 ps ± 100 ppm.

This figures provide the AC test load and signals for the USB, respectively.

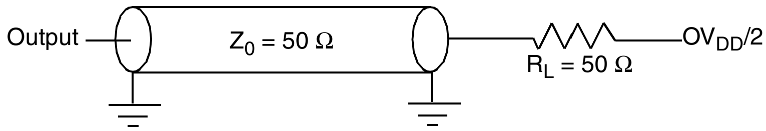

Figure 36. USB AC Test Load

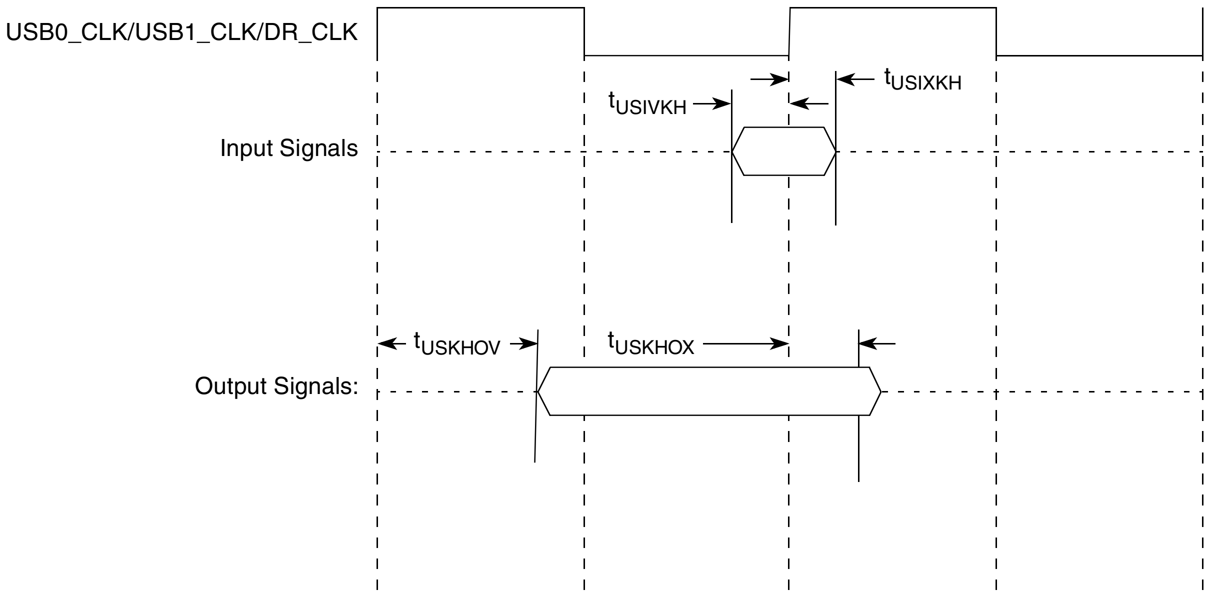

Figure 37. USB Signals

Table 60. Differential Transmitter (TX) Output Characteristics (continued)

Parameter	Symbol	Min	Typical	Max	Units	Notes
TX Common Mode Return loss 150 MHz - 300 MHz 300 MHz - 600 MHz 600 MHz - 1.2 GHz 1.2 GHz - 2.4 GHz 2.4 GHz - 3.0 GHz 3.0 GHz - 5.0 GHz	RL_{SATA_TXCC11}	— — — — — —	— — — — — —	5 5 2 2 1 1	dB	1, 2
TX Impedance Balance 150 MHz - 300 MHz 300 MHz - 600 MHz 600 MHz - 1.2 GHz 1.2 GHz - 2.4 GHz 2.4 GHz - 3.0 GHz 3.0 GHz - 5.0 GHz	RL_{SATA_TXDC11}	— — — — — —	— — — — — —	30 20 10 10 4 4	dB	1, 2
Deterministic jitter 1.5G 3.0G	U_{SATA_TXDJ}	—	—	0.18 0.14	UI	—
Total Jitter 1.5G 3.0G	U_{SATA_TXTJ}	—	—	0.42 0.32	UI	—

Notes:
1. Only applies when operating in 3.0Gb data rate mode.
2. The max value stated for 3.0 GHz - 5.0 GHz range only applies to Gen2i mode and not to Gen2m mode.
3. Only applies to Gen1i mode.

Table 63. I²C DC Electrical Characteristics (continued)

At recommended operating conditions with OV_{DD} of 3.3 V ± 5%.

Parameter	Symbol	Min	Max	Unit	Notes
Pulse width of spikes which must be suppressed by the input filter	t_{I2KHKL}	0	50	ns	2
Input current each I/O pin (input voltage is between 0.1 × OV_{DD} and 0.9 × OV_{DD}(max)	I_I	–10	10	μA	3
Capacitance for each I/O pin	C_I	—	10	pF	—

Notes:

1. Output voltage (open drain or open collector) condition = 3 mA sink current.
2. See the *MPC8536E PowerQUICC III Integrated Processor Reference Manual* for information on the digital filter used.
3. I/O pins will obstruct the SDA and SCL lines if OV_{DD} is switched off.

2.17.2 I²C AC Electrical Specifications

This table provides the AC timing parameters for the I²C interfaces.

Table 64. I²C AC Electrical Specifications

All values refer to V_{IH} (min) and V_{IL} (max) levels (see Table 63).

Parameter	Symbol [1]	Min	Max	Unit	Notes
SCL clock frequency	f_{I2C}	0	400	kHz	—
Low period of the SCL clock	t_{I2CL}	1.3	—	μs	—
High period of the SCL clock	t_{I2CH}	0.6	—	μs	—
Setup time for a repeated START condition	t_{I2SVKH}	0.6	—	μs	—
Hold time (repeated) START condition (after this period, the first clock pulse is generated)	t_{I2SXKL}	0.6	—	μs	—
Data setup time	t_{I2DVKH}	100	—	ns	—
Data hold time: CBUS compatible masters I²C bus devices	t_{I2DXKL}	 — 0	 — —	μs	2
Data output delay time	t_{I2OVKL}	—	0.9	μs	3
Set-up time for STOP condition	t_{I2PVKH}	0.6	—	μs	—
Rise time of both SDA and SCL signals	t_{I2CR}	—	300	ns	4
Fall time of both SDA and SCL signals	t_{I2CF}	—	300	ns	4

2.18 GPIO

This section describes the DC and AC electrical specifications for the GPIO interface of the chip.

2.18.1 GPIO DC Electrical Characteristics

This table provides the DC electrical characteristics for the GPIO interface.

Table 65. GPIO DC Electrical Characteristics

Parameter	Symbol	Min	Max	Unit
High-level input voltage	V_{IH}	2	OV_{DD} + 0.3	V
Low-level input voltage	V_{IL}	– 0.3	0.8	V
Input current (V_{IN} [1] = 0 V or V_{IN} = V_{DD})	I_{IN}	—	±5	μA
High-level output voltage (OV_{DD} = min, I_{OH} = –2 mA)	V_{OH}	2.4	—	V
Low-level output voltage (OV_{DD} = min, I_{OL} = 2 mA)	V_{OL}	—	0.4	V

Note:

1. The symbol V_{IN}, in this case, represents the OV_{IN} symbol referenced in Table 1 and Table 2.

2.18.2 GPIO AC Electrical Specifications

This table provides the GPIO input and output AC timing specifications.

Table 66. GPIO Input and Output AC Timing Specifications[1]

Characteristic	Symbol [2]	Min	Unit	Notes
GPIO inputs—minimum pulse width	t_{PIWID}	7.5	ns	3
GPIO outputs—minimum pulse width	t_{GTOWID}	12	ns	—

Notes:

1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of CLKIN. Timings are measured at the pin.
2. GPIO inputs and outputs are asynchronous to any visible clock. GPIO outputs should be synchronized before use by any external synchronous logic. GPIO inputs are required to be valid for at least t_{PIWID} ns to ensure proper operation.
3. The minimum pulse width is a function of the MPX/Platform clock. The minimum pulse width must be greater than or equal to 4 times the MPX/Platform clock period.

This figure provides the AC test load for the GPIO.

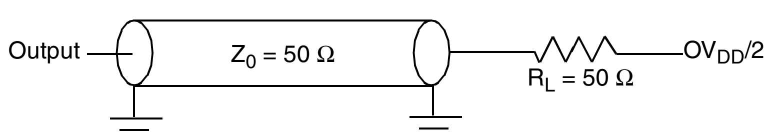

Figure 53. GPIO AC Test Load

— The external reference clock driver must be able to drive this termination.

— The SerDes reference clock input can be either differential or single-ended. See the Differential Mode and Single-ended Mode description below for further detailed requirements.

- The maximum average current requirement that also determines the common mode voltage range

— When the SerDes reference clock differential inputs are DC coupled externally with the clock driver chip, the maximum average current allowed for each input pin is 8mA. In this case, the exact common mode input voltage is not critical as long as it is within the range allowed by the maximum average current of 8 mA (refer to the following bullet for more detail), since the input is AC-coupled on-chip.

— This current limitation sets the maximum common mode input voltage to be less than 0.4 V (0.4 V/50 = 8 mA) while the minimum common mode input level is 0.1V above SnGND (xcorevss). For example, a clock with a 50/50 duty cycle can be produced by a clock driver with output driven by its current source from 0mA to 16mA (0–0.8 V), such that each phase of the differential input has a single-ended swing from 0 V to 800mV with the common mode voltage at 400mV.

— If the device driving the SD*n*_REF_CLK and $\overline{\text{SD}n\text{\_REF\_CLK}}$ inputs cannot drive 50 Ω to SnGND (xcorevss) DC, or it exceeds the maximum input current limitations, then it must be AC-coupled off-chip.

- The input amplitude requirement

— This requirement is described in detail in the following sections.

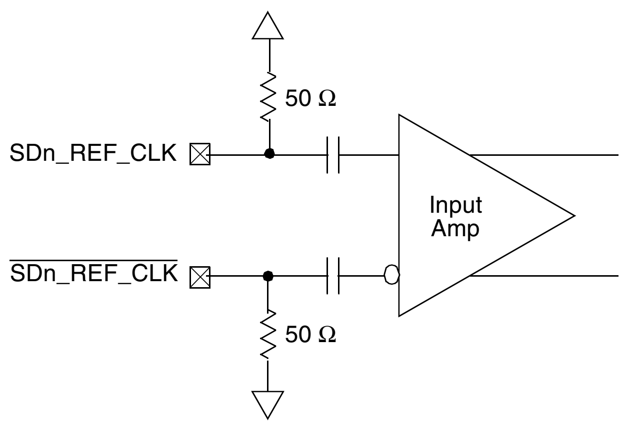

Figure 58. Receiver of SerDes Reference Clocks

2.20.2.4 AC Requirements for SerDes Reference Clocks

The clock driver selected should provide a high quality reference clock with low phase noise and cycle-to-cycle jitter. Phase noise less than 100KHz can be tracked by the PLL and data recovery loops and is less of a problem. Phase noise above 15MHz is filtered by the PLL. The most problematic phase noise occurs in the 1-15MHz range. The source impedance of the clock driver should be 50 ohms to match the transmission line and reduce reflections which are a source of noise to the system.

This table describes some AC parameters common to SGMII and PCI Express protocols.

Table 69. SerDes Reference Clock Common AC Parameters

At recommended operating conditions with XV_{DD_SRDS1} or XV_{DD_SRDS2} = 1.0V ± 5%.

Parameter	Symbol	Min	Max	Unit	Notes
Rising Edge Rate	Rise Edge Rate	1.0	4.0	V/ns	2, 3
Falling Edge Rate	Fall Edge Rate	1.0	4.0	V/ns	2, 3
Differential Input High Voltage	V_{IH}	+200	—	mV	2
Differential Input Low Voltage	V_{IL}	—	–200	mV	2
Rising edge rate (SDn_REF_CLK) to falling edge rate ($\overline{\text{SDn\_REF\_CLK}}$) matching	Rise-Fall Matching	—	20	%	1, 4

Notes:

1. Measurement taken from single ended waveform.
2. Measurement taken from differential waveform.
3. Measured from –200 mV to +200 mV on the differential waveform (derived from SDn_REF_CLK minus $\overline{\text{SDn\_REF\_CLK}}$). The signal must be monotonic through the measurement region for rise and fall time. The 400 mV measurement window is centered on the differential zero crossing. See Figure 66.
4. Matching applies to rising edge rate for SDn_REF_CLK and falling edge rate for $\overline{\text{SDn\_REF\_CLK}}$. It is measured using a 200 mV window centered on the median cross point where SDn_REF_CLK rising meets $\overline{\text{SDn\_REF\_CLK}}$ falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations. The Rise Edge Rate of SDn_REF_CLK should be compared to the Fall Edge Rate of $\overline{\text{SDn\_REF\_CLK}}$, the maximum allowed difference should not exceed 20% of the slowest edge rate. See Figure 67.

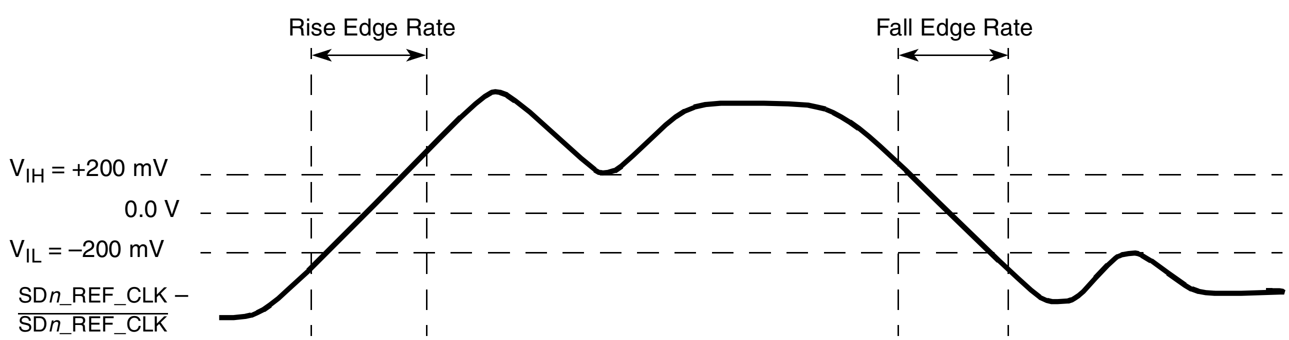

Figure 66. Differential Measurement Points for Rise and Fall Time

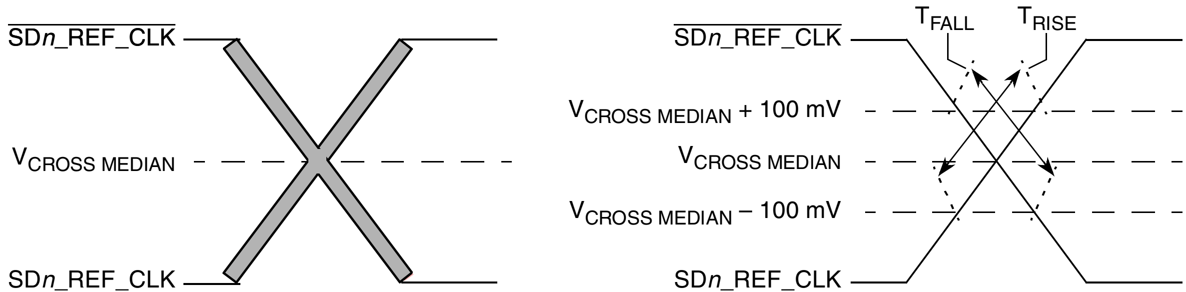

Figure 67. Single-Ended Measurement Points for Rise and Fall Time Matching

The other detailed AC requirements of the SerDes Reference Clocks is defined by each interface protocol based on application usage. See the following sections for detailed information:

- Section 2.9.3.2, "AC Requirements for SGMII SD2_REF_CLK and $\overline{\text{SD2\_REF\_CLK}}$"
- Section 2.21.2, "AC Requirements for PCI Express SerDes Clocks"

2.20.2.4.1 Spread Spectrum Clock

SD1_REF_CLK/$\overline{\text{SD1\_REF\_CLK}}$ were designed to work with a spread spectrum clock (+0 to -0.5% spreading at 30–33 kHz rate is allowed), assuming both ends have same reference clock. For better results, a source without significant unintended modulation should be used.

SD2_REF_CLK/$\overline{\text{SD2\_REF\_CLK}}$ are not intended to be used with, and should not be clocked by, a spread spectrum clock source.

2.20.3 SerDes Transmitter and Receiver Reference Circuits

This figure shows the reference circuits for SerDes data lane's transmitter and receiver.

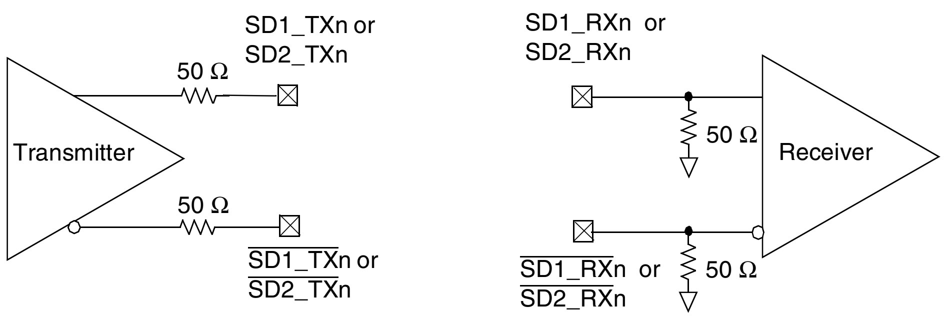

Figure 68. SerDes Transmitter and Receiver Reference Circuits

The DC and AC specification of SerDes data lanes are defined in each interface protocol section below (PCI Express, SATA or SGMII) in this document based on the application usage:

- Section 2.9.3, "SGMII Interface Electrical Characteristics"
- Section 2.21, "PCI Express"
- Section 2.16, "Serial ATA (SATA)"

Please note that external AC Coupling capacitor is required for the above three serial transmission protocols with the capacitor value defined in specification of each protocol section.

2.21 PCI Express

This section describes the DC and AC electrical specifications for the PCI Express bus of the chip.

2.21.1 DC Requirements for PCI Express SD1_REF_CLK and $\overline{\text{SD1\_REF\_CLK}}$

For more information, see Section 2.20.2, “SerDes Reference Clocks.”

2.21.2 AC Requirements for PCI Express SerDes Clocks

This table lists AC requirements.

Table 70. SD1_REF_CLK and $\overline{\text{SD1\_REF\_CLK}}$ AC Requirements

Symbol	Parameter Description	Min	Typical	Max	Units	Notes
t_{REF}	REFCLK cycle time	—	10	—	ns	1
t_{REFCJ}	REFCLK cycle-to-cycle jitter. Difference in the period of any two adjacent REFCLK cycles	—	—	100	ps	—
t_{REFPJ}	Phase jitter. Deviation in edge location with respect to mean edge location	–50	—	50	ps	1,2,3

Notes:
1. Tj at BER of 10E-6 86 ps Max.
2. Total peak-to-peak deterministic jitter “Dj” should be less than or equal to 42 ps.
3. Limits from “PCI Express CEM Rev 2.0” and measured per “PCI Express Rj, D, and Bit Error Rates”.

2.21.3 Clocking Dependencies

The ports on the two ends of a link must transmit data at a rate that is within 600 parts per million 15 (ppm) of each other at all times. This is specified to allow bit rate clock sources with a +/– 300 ppm tolerance.

2.21.4 Physical Layer Specifications

The following is a summary of the specifications for the physical layer of PCI Express on this chip. For further details as well as the specifications of the transport and data link layer, please use the PCI Express Base Specification. REV. 1.0a document.

2.21.4.1 Differential Transmitter (TX) Output

This table defines the specifications for the differential output at all transmitters (TXs). The parameters are specified at the component pins.

Table 71. Differential Transmitter (TX) Output Specifications

Symbol	Parameter	Min	Nom	Max	Units	Comments
UI	Unit Interval	399.88	400	400.12	ps	Each UI is 400 ps ± 300 ppm. UI does not account for Spread Spectrum Clock dictated variations. See Note 1.
$V_{TX\text{-}DIFFp\text{-}p}$	Differential Peak-to-Peak Output Voltage	0.8	—	1.2	V	$V_{TX\text{-}DIFFp\text{-}p} = 2^*\lvert V_{TX\text{-}D+} - V_{TX\text{-}D-}\rvert$ See Note 2.

Table 71. Differential Transmitter (TX) Output Specifications (continued)

Symbol	Parameter	Min	Nom	Max	Units	Comments
$V_{TX-DE-RATIO}$	De- Emphasized Differential Output Voltage (Ratio)	–3.0	–3.5	–4.0	dB	Ratio of the $V_{TX-DIFFp-p}$ of the second and following bits after a transition divided by the $V_{TX-DIFFp-p}$ of the first bit after a transition. See Note 2.
T_{TX-EYE}	Minimum TX Eye Width	0.70	—	—	UI	The maximum Transmitter jitter can be derived as $T_{TX-MAX-JITTER} = 1 – T_{TX-EYE} = 0.3$ UI. See Notes 2 and 3.
$T_{TX-EYE-MEDIAN-to-MAX-JITTER}$	Maximum time between the jitter median and maximum deviation from the median.	—	—	0.15	UI	Jitter is defined as the measurement variation of the crossing points ($V_{TX-DIFFp-p} = 0$ V) in relation to a recovered TX UI. A recovered TX UI is calculated over 3500 consecutive unit intervals of sample data. Jitter is measured using all edges of the 250 consecutive UI in the center of the 3500 UI used for calculating the TX UI. See Notes 2 and 3.
$T_{TX-RISE}$, $T_{TX-FALL}$	D+/D- TX Output Rise/Fall Time	0.125	—	—	UI	See Notes 2 and 5
$V_{TX-CM-ACp}$	RMS AC Peak Common Mode Output Voltage	—	—	20	mV	$V_{TX-CM-ACp} = RMS(\|V_{TXD+} + V_{TXD-}\|/2 – V_{TX-CM-DC})$ $V_{TX-CM-DC} = DC_{(avg)}$ of $\|V_{TX-D+} + V_{TX-D-}\|/2$ See Note 2
$V_{TX-CM-DC-ACTIVE-IDLE-DELTA}$	Absolute Delta of DC Common Mode Voltage During L0 and Electrical Idle	0	—	100	mV	$\|V_{TX-CM-DC\ (during\ L0)} – V_{TX-CM-Idle-DC\ (During\ Electrical\ Idle)}\| <= 100$ mV $V_{TX-CM-DC} = DC_{(avg)}$ of $\|V_{TX-D+} + V_{TX-D-}\|/2$ [L0] $V_{TX-CM-Idle-DC} = DC_{(avg)}$ of $\|V_{TX-D+} + V_{TX-D-}\|/2$ [Electrical Idle] See Note 2.
$V_{TX-CM-DC-LINE-DELTA}$	Absolute Delta of DC Common Mode between D+ and D–	0	—	25	mV	$\|V_{TX-CM-DC-D+} – V_{TX-CM-DC-D-}\| <= 25$ mV $V_{TX-CM-DC-D+} = DC_{(avg)}$ of $\|V_{TX-D+}\|$ $V_{TX-CM-DC-D-} = DC_{(avg)}$ of $\|V_{TX-D-}\|$ See Note 2.
$V_{TX-IDLE-DIFFp}$	Electrical Idle differential Peak Output Voltage	0	—	20	mV	$V_{TX-IDLE-DIFFp} = \|V_{TX-IDLE-D+} - V_{TX-IDLE-D-}\| <= 20$ mV See Note 2.
$V_{TX-RCV-DETECT}$	The amount of voltage change allowed during Receiver Detection	—	—	600	mV	The total amount of voltage change that a transmitter can apply to sense whether a low impedance Receiver is present. See Note 6.
$V_{TX-DC-CM}$	The TX DC Common Mode Voltage	0	—	3.6	V	The allowed DC Common Mode voltage under any conditions. See Note 6.
$I_{TX-SHORT}$	TX Short Circuit Current Limit	—	—	90	mA	The total current the Transmitter can provide when shorted to its ground
$T_{TX-IDLE-MIN}$	Minimum time spent in Electrical Idle	50	—	—	UI	Minimum time a Transmitter must be in Electrical Idle Utilized by the Receiver to start looking for an Electrical Idle Exit after successfully receiving an Electrical Idle ordered set

2.23.1 Clock Ranges

This table provides the clocking specifications for the processor cores and Table 74 provides the clocking specifications for the memory bus.

Table 73. Processor Core Clocking Specifications

Characteristic	Maximum Processor Core Frequency								Unit	Notes
	600 MHz		800 MHz		1000 MHz		1250 MHz			
	Min	Max	Min	Max	Min	Max	Min	Max		
e500 core processor frequency	600	600	600	800	600	1000	600	1250	MHz	1, 2
CCB frequency	400	400	400	400	333	400	333	500		
DDR Data Rate	400	400	400	400	400	400	400	500		

Notes:
1. **Caution:** The CCB to SYSCLK ratio and e500 core to CCB ratio settings must be chosen such that the resulting SYSCLK frequency, e500 (core) frequency, and CCB frequency do not exceed their respective maximum or minimum operating frequencies. See Section 2.23.2, "CCB/SYSCLK PLL Ratio," Section 2.23.3, "e500 Core PLL Ratio,"and Section 2.23.4, "DDR/DDRCLK PLL Ratio," for ratio settings.
2. The processor core frequency speed bins listed also reflect the maximum platform (CCB) and DDR data rate frequency supported by production test. Running CCB and/or DDR data rate higher than the limit shown above, although logically possible via valid clock ratio setting in some condition, is not supported.

The DDR memory controller can run in either synchronous or asynchronous mode. When running in synchronous mode, the memory bus is clocked relative to the platform clock frequency. When running in asynchronous mode, the memory bus is clocked with its own dedicated PLL. This table provides the clocking specifications for the memory bus.

Table 74. Memory Bus Clocking Specifications

Characteristic	Maximum Processor Core Frequency		Unit	Notes
	600, 800, 1000, 1250			
	Min	Max		
DDR Memory bus clock speed	200	250	MHz	1, 2, 3, 4

Notes:
1. **Caution:** The CCB clock to SYSCLK ratio and e500 core to CCB clock ratio settings must be chosen such that the resulting SYSCLK frequency, e500 (core) frequency, and CCB clock frequency do not exceed their respective maximum or minimum operating frequencies. See Section 2.23.2, "CCB/SYSCLK PLL Ratio," Section 2.23.3, "e500 Core PLL Ratio," and Section 2.23.4, "DDR/DDRCLK PLL Ratio," for ratio settings.
2. The Memory bus clock refers to the chip's memory controllers' MCK[0:5] and $\overline{\text{MCK}}$[0:5] output clocks, running at half of the DDR data rate.
3. In synchronous mode, the memory bus clock speed is half the platform clock frequency. In other words, the DDR data rate is the same as the platform (CCB) frequency. If the desired DDR data rate is higher than the platform (CCB) frequency, asynchronous mode must be used.
4. In asynchronous mode, the memory bus clock speed is dictated by its own PLL. See Section 2.23.4, "DDR/DDRCLK PLL Ratio." The memory bus clock speed must be less than or equal to the CCB clock rate which in turn must be less than the DDR data rate.

2.23.6 Frequency Options

2.23.6.1 SYSCLK to Platform Frequency Options

This table shows the expected frequency values for the platform frequency when using a CCB clock to SYSCLK ratio in comparison to the memory bus clock speed.

Table 78. Frequency Options of SYSCLK with Respect to Memory Bus Speeds

CCB to SYSCLK Ratio	SYSCLK (MHz)						
	33.33	41.66	66.66	83	100	111	133.33
	Platform /CCB Frequency (MHz)						
3						333	400
4				333	400	444	
5			333	415	500		
6			400	500			
8		333					
10	333	417					
12	400	500					

2.24 Thermal

This section describes the thermal specifications of the chip.

2.24.1 Thermal Characteristics

This table provides the package thermal characteristics.

Table 79. Package Thermal Characteristics

Characteristic	JEDEC Board	Symbol	Value	Unit	Notes
Junction-to-ambient Natural Convection	Single layer board (1s)	$R_{\theta JA}$	23	°C/W	1, 2
Junction-to-ambient Natural Convection	Four layer board (2s2p)	$R_{\theta JA}$	18	°C/W	1, 2
Junction-to-ambient (@200 ft/min)	Single layer board (1s)	$R_{\theta JA}$	18	°C/W	1, 2

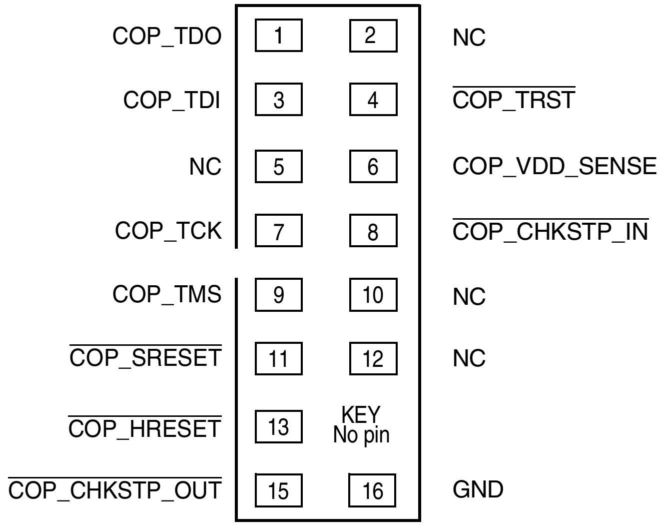

Figure 79. COP Connector Physical Pinout

3.11 Guidelines for High-Speed Interface Termination

3.11.1 SerDes1 Interface Entirely Unused

If the high-speed SerDes interface is not used at all, the unused pin should be terminated as described in this section. However, the SerDes must always have power applied to its supply pins. There are several reserved pins that need to be either left floating or connected to XGND. See SerDes1 in Table 1 for details.

The following pins must be left unconnected (float):

- SD1_TX[7:4]
- SD1_TX[7:4]
- Reserved pins T22, T23

The following pins must be connected to XGND:

- SD1_RX[7:4]
- SD1_RX[7:4]
- SD1_REF_CLK
- SD1_REF_CLK

The POR configuration pin cfg_io_ports[0:2] on TSEC3_TXD[6:3] can be used to power down SerDes 1 block for power saving. Note that both SVDD and XVDD must remain powered.

3.11.2 SerDes 1 Interface Partly Unused

If only part of the high speed SerDes interface pins are used, the remaining high-speed serial I/O pins should be terminated as described in this section.

The following pins must be left unconnected (float) if not used:

- SD1_TX[7:4]
- SD1_TX[7:4]
- Reserved pins: T22, T23